

QUICKSWITCH® PRODUCTS HIGH-SPEED CMOS 10-BIT LOW RESISTANCE BUS SWITCH

IDTQS3R384

FEATURES:

- Enhanced N channel FET with no inherent diode to Vcc
- 2.5 Ω bidirectional switches connect inputs to outputs
- · Zero propagation delay, zero ground bounce
- · Undershoot clamp diodes on all switch and control inputs
- · Two enables control five bits each
- · Available in SOIC and QSOP packages

APPLICATIONS:

- Hot-swapping, hot-docking (low resistance for PCI and Compact PCI applications)
- · Voltage translation (5V to 3.3V)
- Power Conservation
- · Capacitance reduction and isloation
- · Bus Isolation
- · Clock Gating

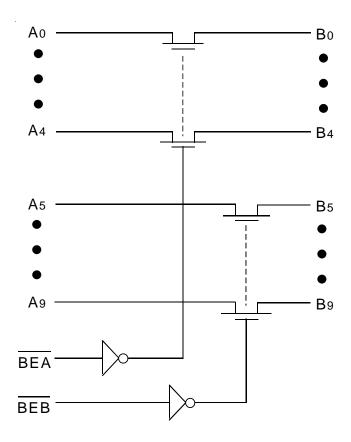
DESCRIPTION:

The QS3R384 provides a set of ten high-speed CMOS TTL-compatible bus switches. Two banks of 5 switches are controlled by independent Bus Enable (\overline{BE}) signals. The very low Ron resistance (2.5 Ω) of the QS3R384 allows inputs to be connected without adding propagation delay and without generating additional ground bounce noise.

The low ON resistance of the QS3R384 makes it ideal for PCI hot-plugging or hot-swapping applications.

The QS3R384 is characterized for operation at -40°C to +85°C.

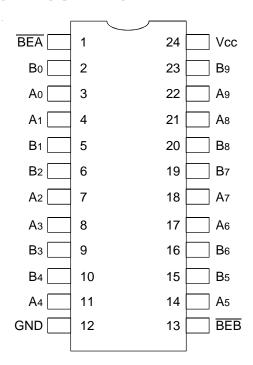
FUNCTIONAL BLOCK DIAGRAM



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PIN CONFIGURATION



SOIC/ QSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Supply Voltage to Ground	-0.5 to +7	V
VTERM ⁽³⁾	DC Switch Voltage Vs	-0.5 to +7	V
VTERM ⁽³⁾	DC Input Voltage VIN	-0.5 to +7	V
VAC	AC Input Voltage (pulse width ≤20ns)	-3	V
Іоит	DC Output Current	120	mA
Рмах	Maximum Power Dissipation (TA = 85°C)	0.5	W
Tstg	Storage Temperature	-65 to +150	°C

NOTES:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
 permanent damage to the device. This is a stress rating only and functional operation
 of the device at these or any other conditions above those indicated in the operational
 sections of this specification is not implied. Exposure to absolute maximum rating
 conditions for extended periods may affect reliability.
- 2. Vcc terminals.
- 3. All terminals except Vcc .

CAPACITANCE (TA = +25°C, f = 1MHz, Vin = 0V, Vout = 0V)

Pins	Тур.	Max. ⁽¹⁾	Unit
Control Inputs	3	4	pF
Quickswitch Channels (Switch OFF)	5	6	рF

NOTE:

1. This parameter is guaranteed but not production tested.

PIN DESCRIPTION

Pin Names	I/O	Description		
A0 - A9	I/O	Bus A		
Bo - B9	I/O	Bus B		
BEA, BEB	I	Bus Switch Enable		

FUNCTION TABLE(1)

BEA	BEB	B0 - A4	B5 - B9	Function
Н	Н	Hi-Z	Hi-Z	Disconnect
L	Н	A0 - A4	Hi-Z	Connect
Н	L	Hi-Z	A5 - A9	Connect
L	L	A0 - A4	A5 - A9	Connect

NOTE:

- 1. H = HIGH Voltage Level
 - L = LOW Voltage Level
 - Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

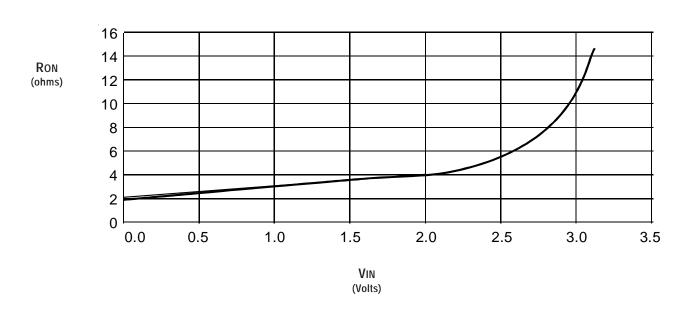
Industrial: TA = -40°C to +85°C, VCC = $5V \pm 10\%$

Symbol	Parameter	Test Conditions	Min.	Typ. ⁽¹⁾	Max.	Unit
VIH	Input HIGH Voltage	Guaranteed Logic HIGH for Control Pins	2	_	_	V
VIL	Input LOW Voltage	Guaranteed Logic LOW for Control Pins	-	_	8.0	V
lin	Input Leakage Current (Control Inputs)	0V ≤ VIN ≤ VCC	_	0.01	±1	μA
loz	Off-State Current (Hi-Z)	0V ≤ Vouт ≤ Vcc, Switches OFF	_	0.01	±1	μA
Ron	Switch ON Resistance ⁽²⁾	Vcc = Min., VIN = 0V, ION = 30mA		2.5	5	Ω
		VCC = Min., VIN = 2.4V, ION = 15mA	_	4	8.5	
VP	Pass Voltage ⁽³⁾	$V_{IN} = V_{CC} = 5V$, $I_{OUT} = -5\mu A$	3.7	4	4.3	V

NOTES:

- 1. Typical values are at Vcc = 5V and TA = 25°C.
- 2. Max value of Ron is guaranteed but not production tested.
- 3. Pass voltage is guaranteed but not production tested.

TYPICAL ON RESISTANCE vs Vin AT Vcc = 5V



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POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾	Max.	Unit
Icco	Quiescent Power Supply Current	Vcc = Max., Vin = GND or Vcc, f = 0	1.5	μА
Δlcc	Power Supply Current per Input HIGH(2)	Vcc = Max., Vin = 3.4V, f = 0	2.5	mA
ICCD	Dynamic Power Supply Current per MHz ⁽³⁾	Vcc = Max., A and B Pins Open, Control Inputs Toggling @ 50% Duty Cycle	0.25	mA/MHz

NOTES:

- 1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- 2. Per TTL-driven input (ViN = 3.4V, control inputs only). A and B pins do not contribute to Δlcc.
- 3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $T_A = -40^{\circ}C \text{ to } +85^{\circ}C, V_{CC} = 5V \pm 10\%$

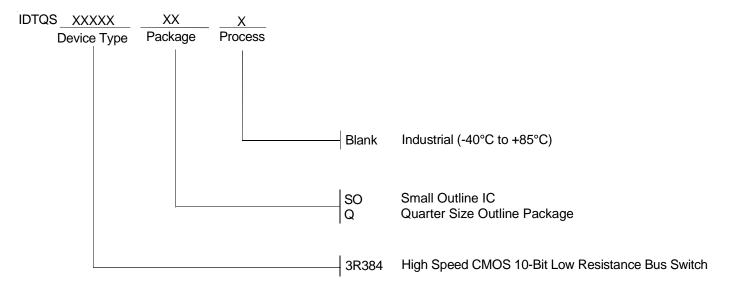
CLOAD = 50pF, RLOAD = 500Ω unless otherwise noted.

Symbol	Parameter	Min. ⁽¹⁾	Тур.	Max.	Unit
tplh	Data Propagation Delay ⁽²⁾	_	_	0.12 ⁽³⁾	ns
t _{PHL}	Ax to Bx, Bx to Ax				
tpzl	Switch Turn-On Delay	1.5	_	6	ns
tpzh	BEA, BEB to Ax, Bx				
tplz	Switch Turn-Off Delay ⁽²⁾	1.5	_	4	ns
tphz	BEA, BEB to Ax, Bx				

NOTES:

- 1. Minimums are guaranteed but not production tested.
- 2. This parameter is guaranteed but not production tested.
- 3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.12ns at C_L = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

ORDERING INFORMATION





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